

**D3FP3****30V 3A****特長**

- 小型SMD
- 超低  $V_F=0.4V$

**Feature**

- Small SMD
- Ultra-Low  $V_F=0.4V$

**用途**

- バッテリー逆接続防止
- DC出力OR用
- DC/DCコンバータ
- 携帯電話、パソコン

**Main Use**

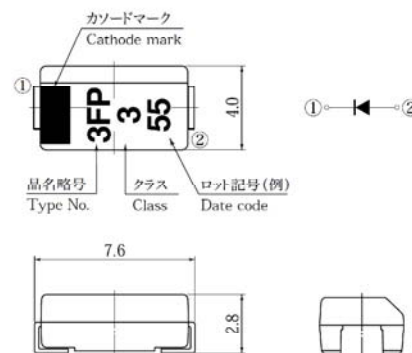
- Reverse connect protection for DC power source
- DC OR-output
- DC/DC Converter
- Mobile phone, PC

**■外観図 OUTLINE**

Package : 2F

Unit:mm

Weight 0.16g (Typ)



外形図については新電元Webサイト又は〈半導体製品一覧表〉をご参照下さい。捺印表示については捺印仕様をご確認下さい。

For details of the outline dimensions, refer to our web site or Semiconductor Short Form Catalog. As for the marking, refer to the specification "Marking, Terminal Connection".

**■定格表 RATINGS****●絶対最大定格 Absolute Maximum Ratings** (指定のない場合  $T_I = 25^\circ C$ )

| 項目<br>Item                                             | 記号<br>Symbol | 条件<br>Conditions                                                                                                      | 品名<br>Type No. | D3FP3     | 単位<br>Unit |
|--------------------------------------------------------|--------------|-----------------------------------------------------------------------------------------------------------------------|----------------|-----------|------------|
| 保存温度<br>Storage Temperature                            | $T_{stg}$    |                                                                                                                       |                | -55 ~ 125 | $^\circ C$ |
| 接合部温度<br>Operation Junction Temperature                | $T_j$        |                                                                                                                       |                | 125       | $^\circ C$ |
| せん頭逆電圧<br>Maximum Reverse Voltage                      | $V_{RM}$     |                                                                                                                       |                | 30        | V          |
| 繰り返しせん頭サージ逆電圧<br>Repetitive Peak Surge Reverse Voltage | $V_{RRSM}$   | パルス幅0.5ms, duty 1/40<br>Pulse width 0.5ms, duty 1/40                                                                  |                | 35        | V          |
| 出力電流<br>Average Rectified Forward Current              | $I_o$        | 50Hz 正弦波, 抵抗負荷, $T_I = 74^\circ C$<br>50Hz sine wave, Resistance load, $T_I = 74^\circ C$                             |                | 3         | A          |
| せん頭サージ順電流<br>Peak Surge Forward Current                | $I_{FSM}$    | 50Hz 正弦波, 非繰り返し1サイクルせん頭値, $T_j = 25^\circ C$<br>50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j = 25^\circ C$ |                | 150       | A          |

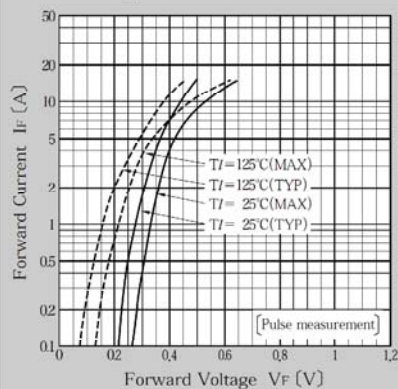
**●電氣的・熱的特性 Electrical Characteristics** (指定のない場合  $T_I = 25^\circ C$ )

|                              |               |                                                                          |          |              |
|------------------------------|---------------|--------------------------------------------------------------------------|----------|--------------|
| 順電圧<br>Forward Voltage       | $V_F$         | $I_F = 1.6A$ , パルス測定<br>Pulse measurement                                | MAX 0.35 | V            |
|                              |               | $I_F = 4A$ , パルス測定<br>Pulse measurement                                  | MAX 0.40 |              |
| 逆電流<br>Reverse Current       | $I_R$         | $V_R = V_{RM}$ , パルス測定<br>Pulse measurement                              | MAX 10   | mA           |
| 接合容量<br>Junction Capacitance | $C_j$         | $f = 1MHz$ , $V_R = 10V$                                                 | TYP 300  | pF           |
| 熱抵抗<br>Thermal Resistance    | $\theta_{jl}$ | 接合部・リード間<br>Junction to lead                                             | MAX 24   | $^\circ C/W$ |
|                              | $\theta_{ja}$ | 接合部・周囲間<br>Junction to ambient                                           | MAX 90   |              |
|                              |               | アルミナ基板実装<br>On alumina substrate<br>プリント基板実装<br>On glass-epoxy substrate | MAX 120  |              |

## ■特性図 CHARACTERISTIC DIAGRAMS

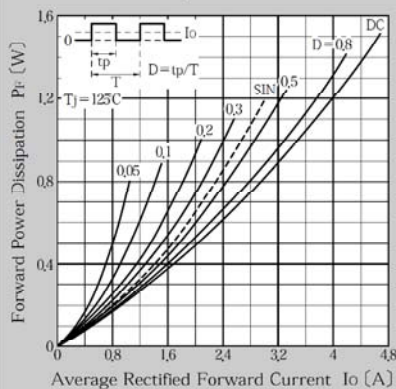
順方向特性

Forward Voltage



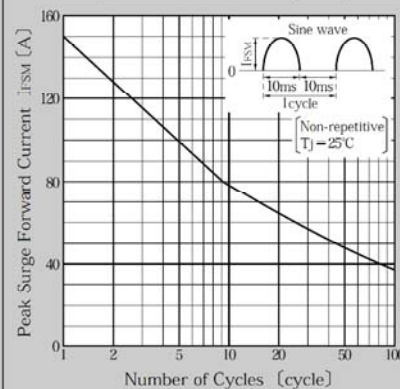
順電力損失曲線

Forward Power Dissipation



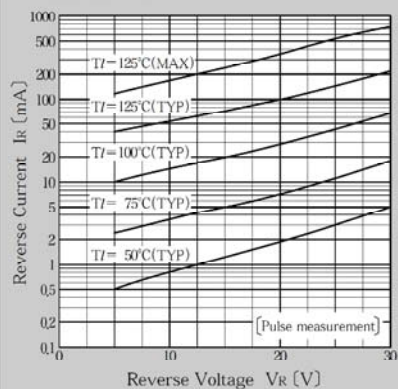
せん頭サージ順電流耐量

Peak Surge Forward Current Capability



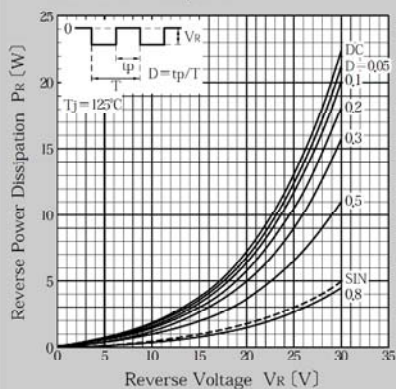
逆方向特性

Reverse Current



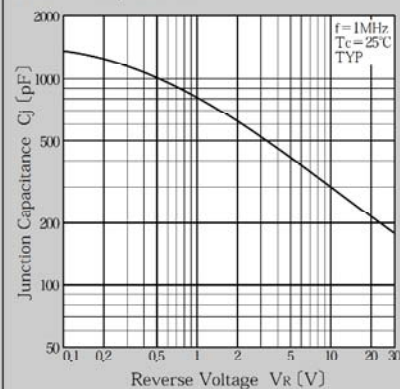
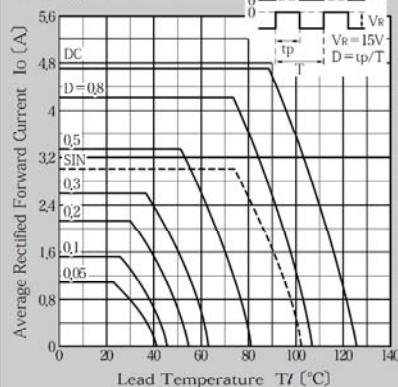
逆電力損失曲線

Reverse Power Dissipation



接合容量

Junction Capacitance

ディレーティングカーブ  $T_J$ - $I_O$ Derating Curve  $T_J$ - $I_O$ 

- \* Sine waveは50Hzで測定しています。
- \* 50Hz sine wave is used for measurements.
- \* 半導体製品の特性は一般的にバラツキを持っています。
- \* Typical is statistical average of the device's ability.
- \* Semiconductor products generally have characteristic variation.
- \* Typical is a statistical average of the device's ability.